NSN 5962-01-257-3036

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View Online at https://aerobasegroup.com/nsn/5962-01-257-3036

Overall Height:

Between 0.290 inches and 0.380 inches

Overall Width:

Between 0.300 inches and 0.395 inches

Body Length:

Between 0.755 inches and 0.785 inches

Body Width:

0.302 inches

Body Height:

Between 0.145 inches and 0.175 inches

Maximum Power Dissipation Rating:

614.4 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Burn in and bipolar and hermetically sealed and schottky and programmable and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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